

DMS2220LFDB P-CHANNEL ENHANCEMENT MODE MOSFET WITH INTEGRATED SBR® SUPER BARRIER RECTIFIER

Features

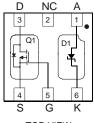
- Low On-Resistance
 - $95m\Omega @V_{GS} = -4.5V$ ٠
 - $120m\Omega @V_{GS} = -2.5V$.
 - $86m\Omega$ (typ) @V_{GS} = -1.8V •
 - Low Gate Threshold Voltage, -1.3V Max
- Fast Switching Speed
- Low Input/Output Leakage
- Incorporates Low V_F Super Barrier Rectifier (SBR®)
- Low Profile, 0.5mm Max Height
- Lead Free/RoHS Compliant (Note 2)
- "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: DFN2020B-6
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminal Connections: See Diagram
- Terminals: Finish NiPdAu over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Marking Information: See Page 6
- Ordering Information: See Page 6
- Weight: 0.0065 grams (approximate)



BOTTOM VIEW



DFN2020B-6

TOP VIEW Internal Schematic



BOTTOM VIEW Pin Configuration

Maximum Ratings – TOTAL DEVICE @TA = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 1)	PD	1.4	W
Thermal Resistance, Junction to Ambient	$R_{ ext{ heta}JA}$	89	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Maximum Ratings – P-CHANNEL MOSFET – Q1 @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Units
Drain-Source Voltage	V _{DSS}	-20	V
Gate-Source Voltage	V _{GSS}	±12	V
Drain Current (Note 1)	ID	-3.5	A
Pulsed Drain Current (Note 4)	I _{DM}	-12	A

Maximum Ratings – SBR[®] – D1 @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	35	V
RMS Reverse Voltage	V _{R(RMS)}	25	V
Average Rectified Output Current	lo	1	A
Non-Repetitive Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load	I _{FSM}	3	А

1. Device mounted on FR-4 PCB, on minimum recommended, 2oz Copper pad layout.

No purposefully added lead. 2.

Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php. Repetitive rating, pulse width limited by junction temperature. 3.

4.

SBR is a registered trademark of Diodes Incorporated.

Notes:



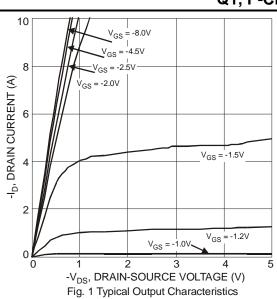
Electrical Characteristics – P-CHANNEL MOSFET – Q1 @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 5)						
Drain-Source Breakdown Voltage	BV _{DSS}	-20		_	V	$V_{GS} = 0V, I_D = -250 \mu A$
Zero Gate Voltage Drain Current	I _{DSS}	_		-1	μA	$V_{DS} = -20V, V_{GS} = 0V$
Gate-Source Leakage		_	_	±100 ±800	nA	$V_{GS} = \pm 8V$, $V_{DS} = 0V$ $V_{GS} = \pm 12V$, $V_{DS} = 0V$
ON CHARACTERISTICS (Note 5)						
Gate Threshold Voltage	V _{GS(th)}	-0.45		-1.3	V	$V_{DS} = V_{GS}, I_D = -250 \mu A$
Static Drain-Source On-Resistance	R _{DS (ON)}		60 74 86	95 120 —	mΩ	$V_{GS} = -4.5V, I_D = -2.8A$ $V_{GS} = -2.5V, I_D = -2.0A$ $V_{GS} = -1.8V, I_D = -1.0A$
Forward Transfer Admittance	Y _{fs}		8	_	S	V _{DS} = -5V, I _D = -2.8A
Diode Forward Voltage (Note 5)	V _{SD}	_	0.7	-1.2	V	$V_{GS} = 0V, I_{S} = -1.6A$
DYNAMIC CHARACTERISTICS				_		
Input Capacitance	C _{iss}		632		pF	
Output Capacitance	C _{oss}	_	65	_	pF	V _{DS} = -10V, V _{GS} = 0V f = 1.0MHz
Reverse Transfer Capacitance	C _{rss}		54	_	pF	

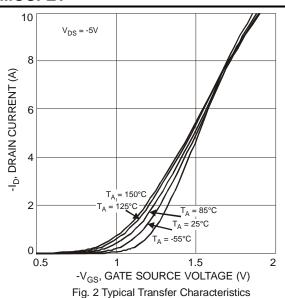
Electrical Characteristics – SBR[®] – D1 @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 5)	V _{(BR)R}	35	40		V	I _R = 1mA
Forward Voltage	VF		354 415	0.42 0.49	V	I _F = 0.5A I _F = 1.0A
Reverse Current (Note 5)	I _R		_	100	μΑ	V _R = 20V

Notes: 5. Short duration pulse test used to minimize self-heating effect.



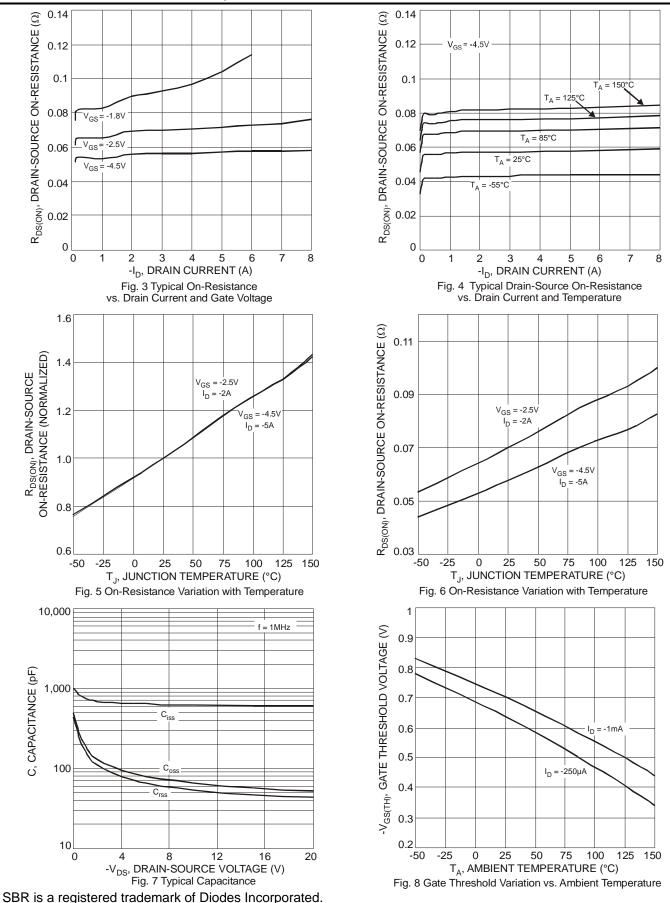
Q1, P-CHANNEL MOSFET



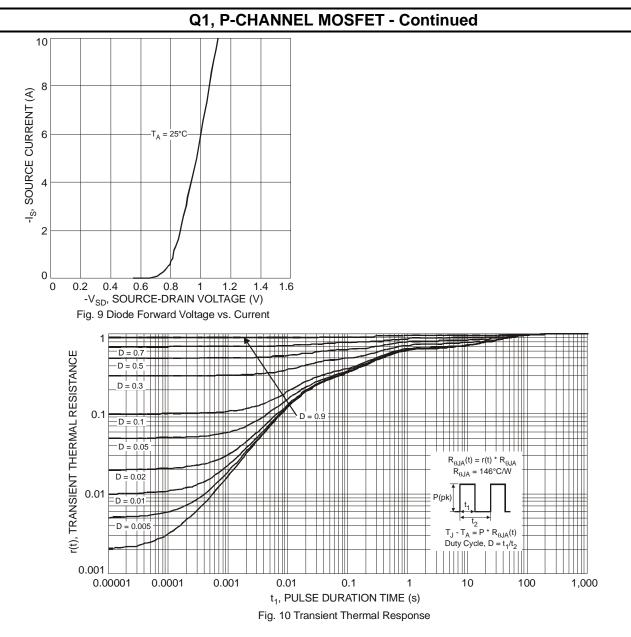


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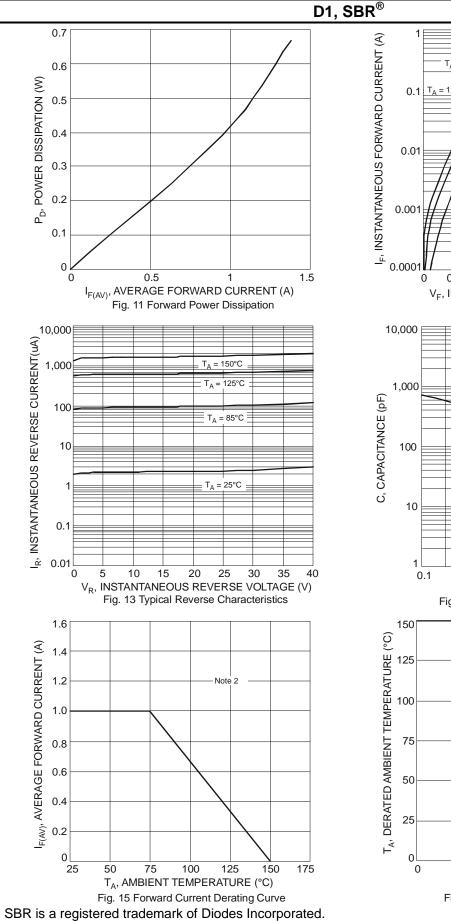


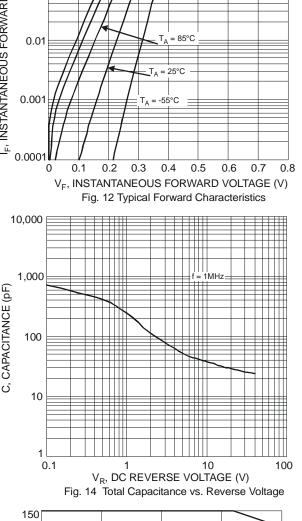




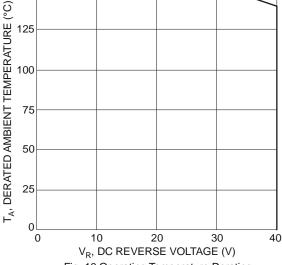


DMS2220LFDB





T_A = 150°C





Ordering Information (Note 6)

Part Number	Case	Packaging
DMS2220LFDB-7	DFN2020B-6	3000/Tape & Reel

Notes: 6. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information

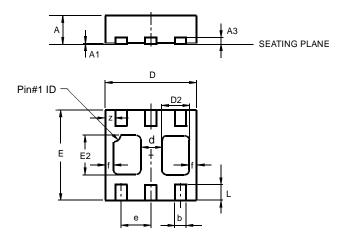


ME = Marking Code YM = Date Code Marking Y = Year (ex: V = 2008) M = Month (ex: 9 = September) Dot denotes Pin 1

Date Code Key

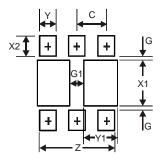
Year	2008		2009	2010		2011	2012		2013	2014		2015
Code	V		W	Х		Y	Z		А	В		С
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

Package Outline Dimensions



	DFN2020B-6								
Dim	Min	Max	Тур						
Α	0.545	0.605	0.575						
A1	0	0.05	0.02						
A3	_		0.13						
b	0.20	0.30	0.25						
D	1.95	2.075	2.00						
d	_		0.45						
D2	0.50	0.70	0.60						
е			0.65						
Е	1.95	2.075	2.00						
E2	0.90	1.10	1.00						
f		_	0.15						
L	0.25	0.35	0.30						
z	_	_	0.225						
All	Dimens	ions in	mm						

Suggested Pad Layout



Dimensions	Value (in mm)
Z	1.67
G	0.20
G1	0.40
X1	1.0
X2	0.45
Y	0.37
Y1	0.70
С	0.65



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